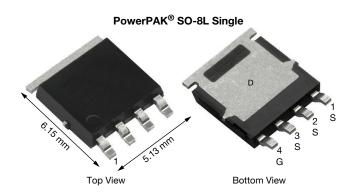
Vishay Siliconix

Automotive N-Channel 40 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY				
V _{DS} (V)	40			
$R_{DS(on)}$ (Ω) at $V_{GS} = 10 \text{ V}$	0.00300			
I _D (A)	60			
Configuration	Single			
Package	PowerPAK SO-8L			

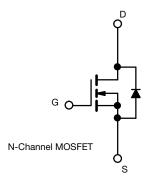
FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % Rq and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





HALOGEN FREE



ABSOLUTE MAXIMUM RATING		SYMBOL	LIMIT	UNIT	
PARAMETER		STIVIDUL		UNIT	
Drain-Source Voltage		V _{DS}	40	V	
Gate-Source Voltage		V_{GS}	± 20		
Continuous Drain Current ^a	T _C = 25 °C	1	60		
	T _C = 125 °C	Ι _D	60		
Continuous Source Current (Diode conduction) a		I _S	60	А	
Pulsed Drain Current b		I _{DM}	150		
Single Pulse Avalanche Current		I _{AS}	45		
Single Pulse Avalanche Energy	L = 0.1 mH	E _{AS}	101	mJ	
Maximum Power Dissipation ^b	T _C = 25 °C	D	68	w	
	T _C = 125 °C	P_{D}	22		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +175	°C	
Soldering Recommendations (Peak temperature) d, e		·	260	°C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient PC	CB mount c	R_{thJA}	68	°C/W
Junction-to-Case (Drain)		R_{thJC}	2.2	C/VV

Notes

- a. Package limited.
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.
- c. When mounted on 1" square PCB (FR4 material).
- d. See solder profile (www.vishay.com/doc?73257). The PowerPAK SO-8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.



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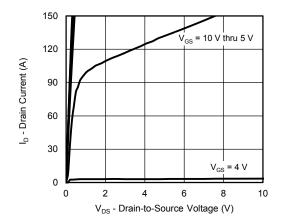
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} = 0, I _D = 250 μA		40	-	-	V
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}, I_{D} = 250 \mu\text{A}$		3.0	3.5	V
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	-	± 100	nA
Zero Gate Voltage Drain Current		V _{GS} = 0 V	V _{DS} = 40 V	-	=	1	
	I _{DSS}	V _{GS} = 0 V	V _{DS} = 40 V, T _J = 125 °C	-	-	50	μA
		V _{GS} = 0 V	V _{DS} = 40 V, T _J = 175 °C	-	-	250	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	30	=	-	Α
Drain-Source On-State Resistance ^a		V _{GS} = 10 V	I _D = 10 A	-	0.00245	0.00300	
	R _{DS(on)}	V _{GS} = 10 V	I _D = 10 A, T _J = 125 °C	-	-	0.00440	Ω
		V _{GS} = 10 V	I _D = 10 A, T _J = 175 °C	-	-	0.00520	
Forward Transconductance b	9 _{fs}	V _{DS} = 15 V, I _D = 10 A		-	67	-	S
Dynamic ^b							
Input Capacitance	C _{iss}			-	3850	5000	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	$V_{DS} = 25 \text{ V, f} = 1 \text{ MHz}$	-	2300	3050	pF
Reverse Transfer Capacitance	C _{rss}				70	100	
Total Gate Charge ^c	Qg			-	67	105	
Gate-Source Charge ^c	Q_{gs}	V _{GS} = 10 V	$V_{DS} = 20 \text{ V}, I_{D} = 5 \text{ A}$	-	19	-	nC
Gate-Drain Charge ^c	Q _{gd}			-	9	-	
Gate Resistance	R_g	f = 1 MHz		0.24	0.49	0.75	Ω
Turn-On Delay Time ^c	t _{d(on)}			-	18	30	
Rise Time ^c	t _r	V_{DD} = 20 V, R_L = 4 Ω $I_D \cong$ 5 A, V_{GEN} = 10 V, R_g = 1 Ω		-	5	10	ns ns
Turn-Off Delay Time ^c	t _{d(off)}			-	30	50	
Fall Time ^c	t _f			-	15	25	
Source-Drain Diode Ratings and Char	racteristics ^b						
Pulsed Current ^a	I _{SM}			-	-	150	Α
Forward Voltage	V_{SD}	I _F = 15 A, V _{GS} = 0			0.81	1.20	V

Notes

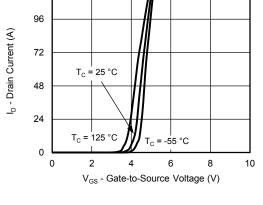
- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



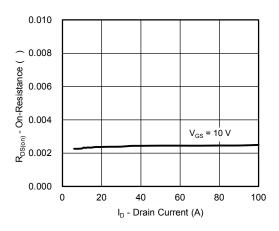


Output Characteristics

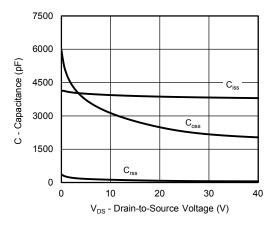


120

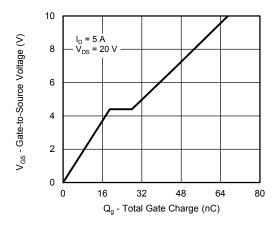
Transfer Characteristics



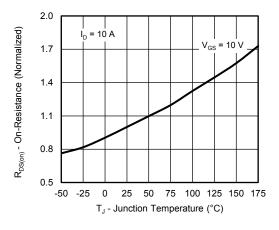
On-Resistance vs. Drain Current



Capacitance

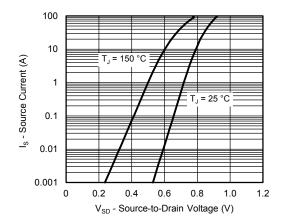


Gate Charge

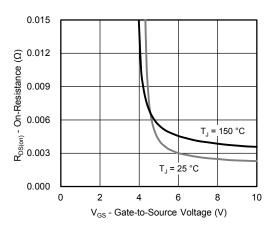


On-Resistance vs. Junction Temperature

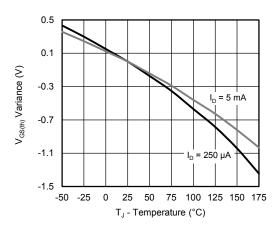




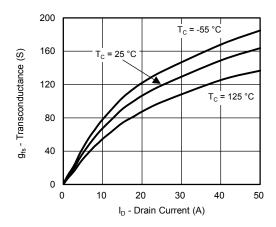
Source Drain Diode Forward Voltage



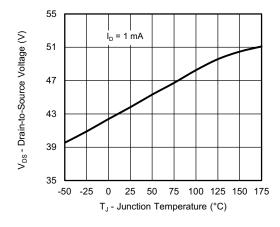
On-Resistance vs. Gate-to Source Voltage



Threshold Voltage

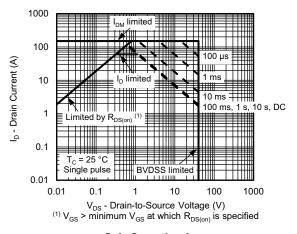


Transconductance

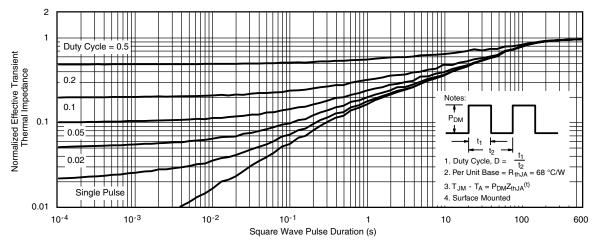


Drain Source Breakdown vs. Junction Temperature



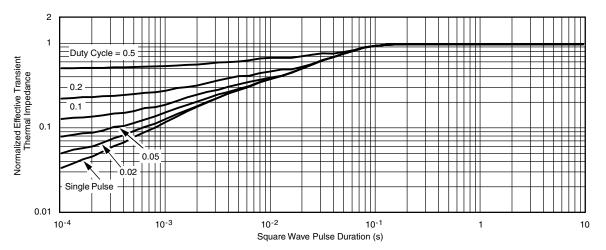


Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient





Normalized Thermal Transient Impedance, Junction-to-Case

Note

The characteristics shown in the two graphs

S16-1488-Rev. A, 01-Aug-16

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?76495.



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